NSN 5961-00-211-7033

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Inclosure Material:

Metal

Overall Length:

1.330 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

300.0 breakdown voltage, collector-to-emitter, base open and 300.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, dc

Current Rating Per Characteristic:

Between 7.50 amperes source cutoff current and 3.00 amperes source cutoff current and 8.00 amperes source cutoff current blank

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector preset

Transfer Ratio:

100.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 wire hook

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0